

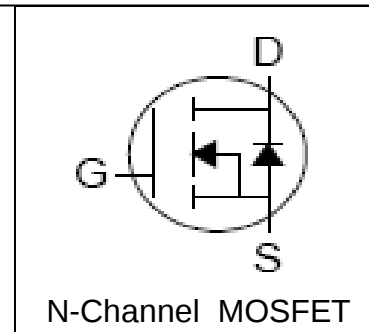
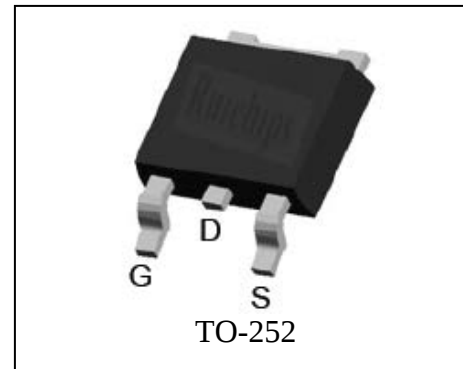
Features

- 600V/1.2A,
 $R_{DS(ON)} = 10\Omega$ (Typ.) @ $V_{GS} = 10V$
- Gate charge minimized
- Low C_{rss} (Typ. 4pF)
- Extremely high dv/dt capability
- 100% avalanche tested
- Lead Free and Green Available

Applications

- High efficiency switch mode power supplies
- Lighting

Pin Description



Absolute Maximum Ratings

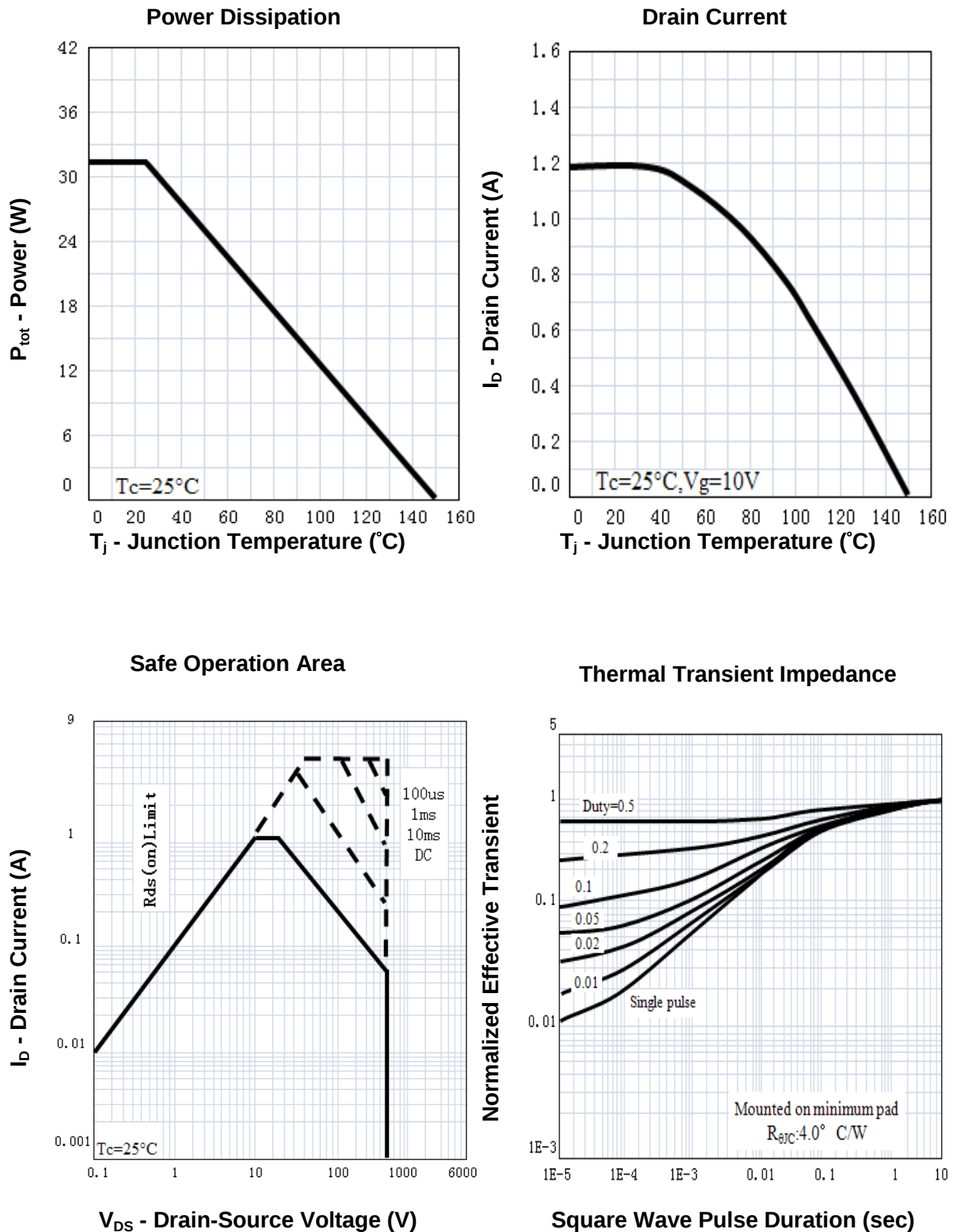
Symbol	Parameter		Rating	Unit
Common Ratings (T _C =25°C Unless Otherwise Noted)				
V _{DSS}	Drain-Source Voltage		600	V
V _{GSS}	Gate-Source Voltage		±30	
T _J	Maximum Junction Temperature		150	°C
T _{STG}	Storage Temperature Range		-55 to 150	°C
I _S	Diode Continuous Forward Current	T _C =25°C	1.2	A
Mounted on Large Heat Sink				
I _{DP}	300μs Pulse Drain Current Tested	T _C =25°C	4.8 ^①	A
I _D	Continuous Drain Current	T _C =25°C	1.2 ^②	A
		T _C =100°C	0.78	
P _D	Maximum Power Dissipation	T _C =25°C	31	W
		T _C =100°C	13	
R _{θJC}	Thermal Resistance-Junction to Case		4.0	°C/W
Drain-Source Avalanche Ratings				
E _{AS} ^③	Avalanche Energy, Single Pulsed		1.5	mJ

Electrical Characteristics ($T_C=25^{\circ}\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU6H1L			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _{DS} =250μA	600			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =600V, V _{GS} =0V T _J =85°C			1 30	μA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250μA	2	3	4	V
I _{GSS}	Gate Leakage Current	V _{GS} =±30V, V _{DS} =0V			±100	nA
R _{DS(ON)} ^④	Drain-Source On-state Resistance	V _{GS} =10V, I _{DS} =0.6A		10	11.5	Ω
Diode Characteristics						
V _{SD} ^④	Diode Forward Voltage	I _{SD} =1.2A, V _{GS} =0V			1.4	V
t _{rr}	Reverse Recovery Time	I _{SD} =1.2A, dI _{SD} /dt=100A/μs		195		ns
Q _{rr}	Reverse Recovery Charge			0.55		μC
Dynamic Characteristics ^⑤						
R _G	Gate Resistance	V _{GS} =0V, V _{DS} =0V, F=1MHz		10		Ω
C _{iSS}	Input Capacitance	V _{GS} =0V, V _{DS} =300V, Frequency=1.0MHz		135		pF
C _{oSS}	Output Capacitance			23		
C _{rSS}	Reverse Transfer Capacitance			4		
t _{d(ON)}	Turn-on Delay Time	V _{DD} =300V, R _L =250Ω, I _{DS} =1.2A, V _{GEN} =10V, R _G =25Ω		7		ns
t _r	Turn-on Rise Time			20		
t _{d(OFF)}	Turn-off Delay Time			15		
t _f	Turn-off Fall Time			30		
Gate Charge Characteristics ^⑤						
Q _g	Total Gate Charge	V _{DS} =480V, V _{GS} = 10V, I _{DS} =1.2A		5.5		nC
Q _{gs}	Gate-Source Charge			0.7		
Q _{gd}	Gate-Drain Charge			2.7		

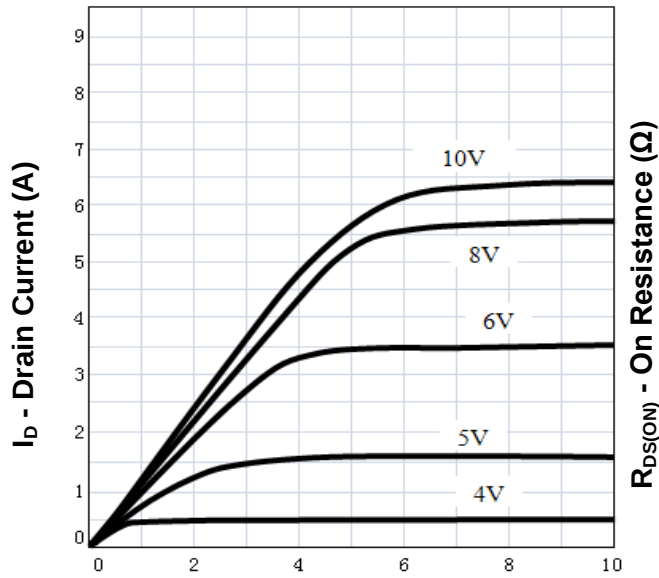
- Notes: ① Pulse width limited by safe operating area.
 ② Current limited by maximum junction temperature.
 ③ Limited by $T_{Jmax}, I_{AS}=1.75A, V_{DD}=100V, R_G=50\Omega$, Starting $T_J=25^{\circ}\text{C}$.
 ④ Pulse test; Pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
 ⑤ Guaranteed by design, not subject to production testing.

Typical Characteristics

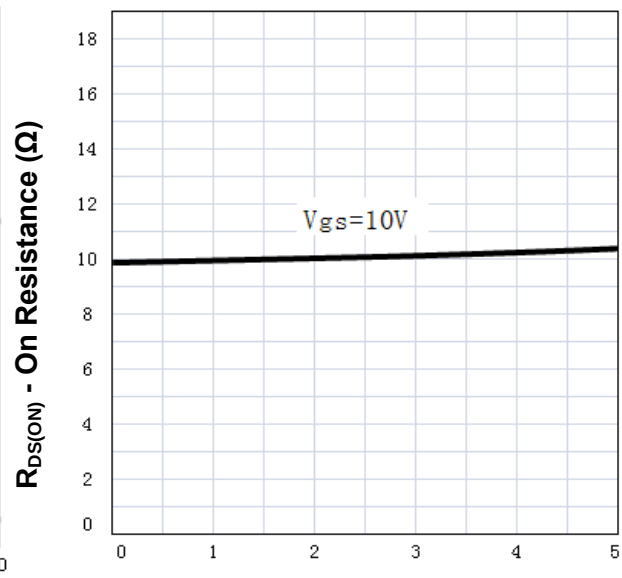


Typical Characteristics

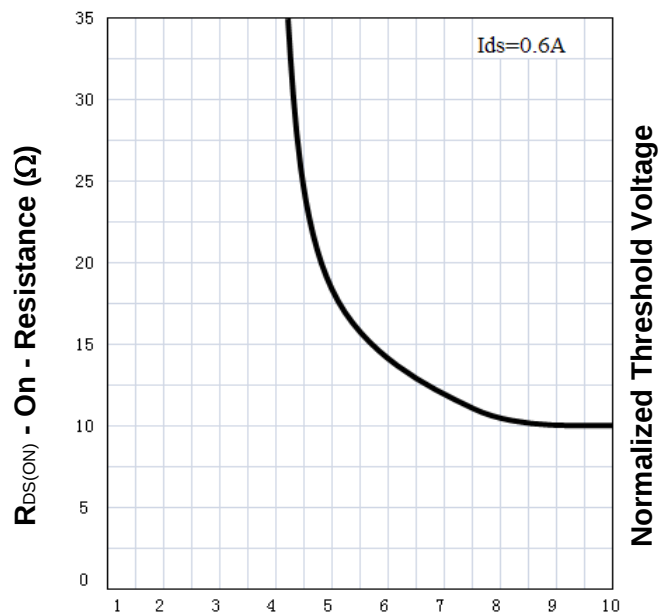
Output Characteristics



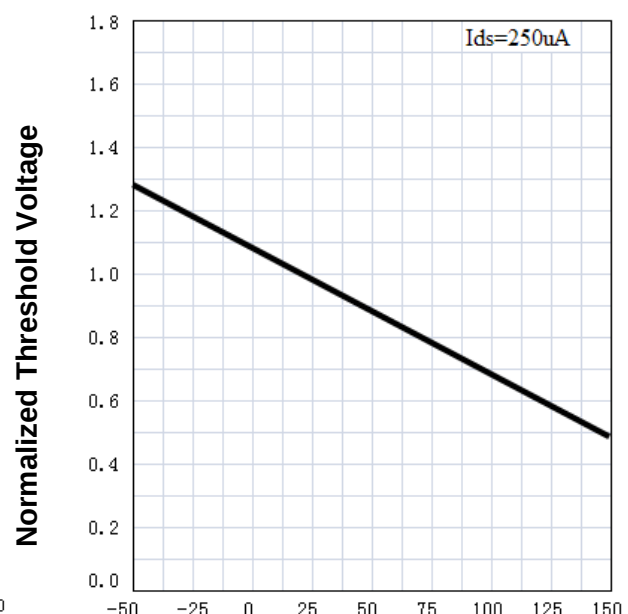
Drain-Source On Resistance



Drain-Source On Resistance



Gate Threshold Voltage

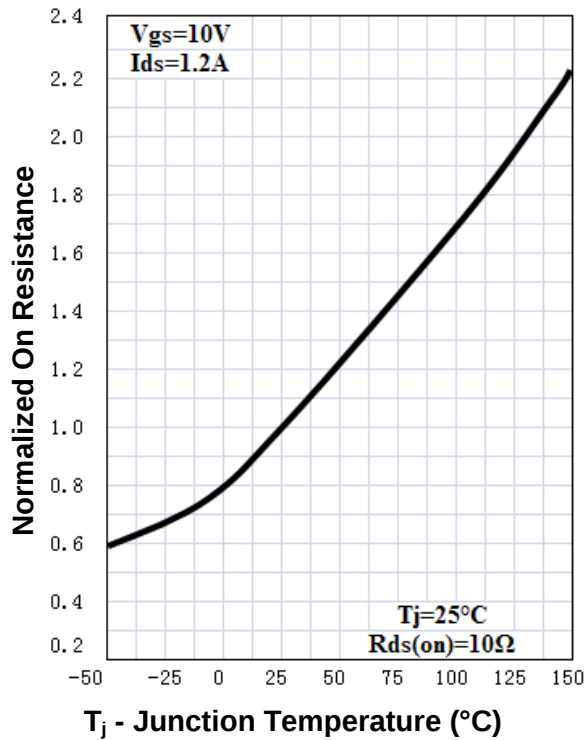


V_{GS} - Gate-Source Voltage (V)

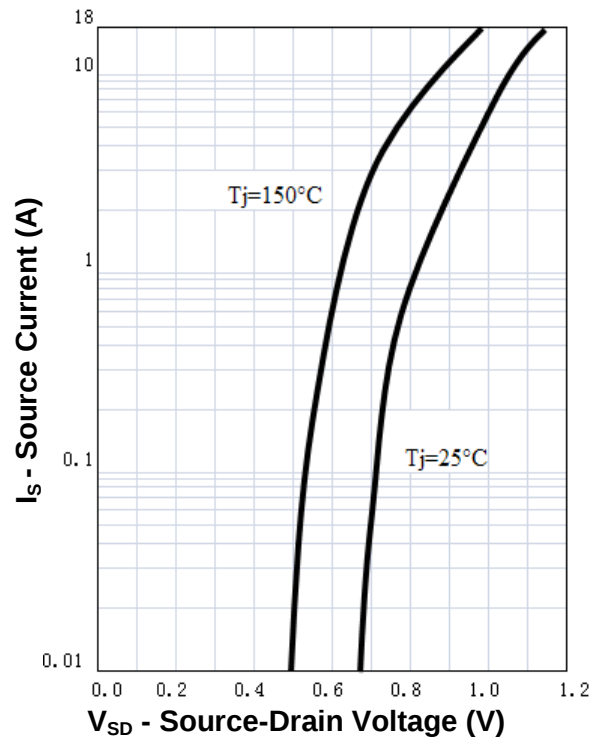
T_J - Junction Temperature ($^{\circ}C$)

Typical Characteristics

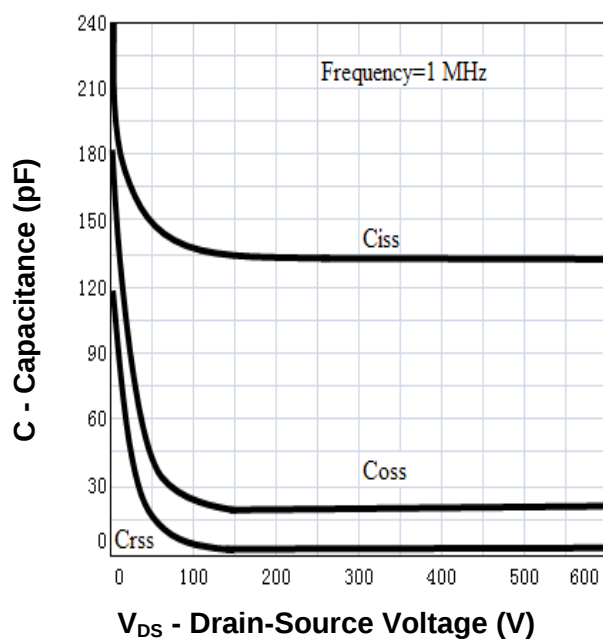
Drain-Source On Resistance



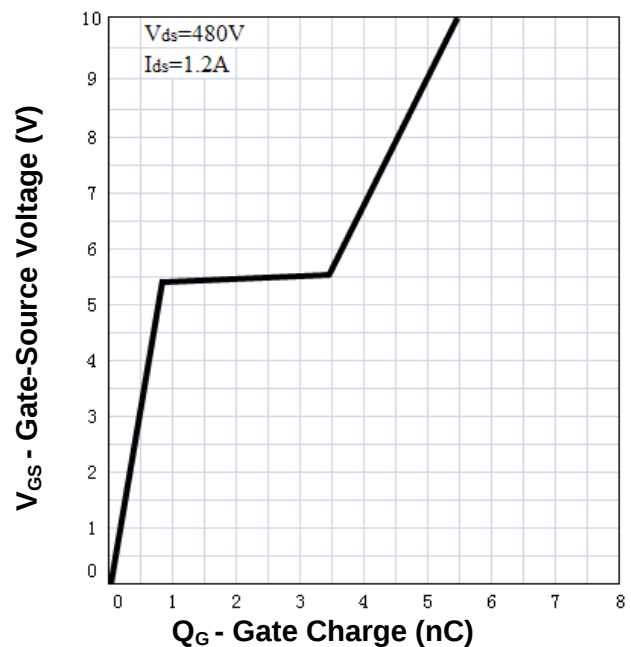
Source-Drain Diode Forward



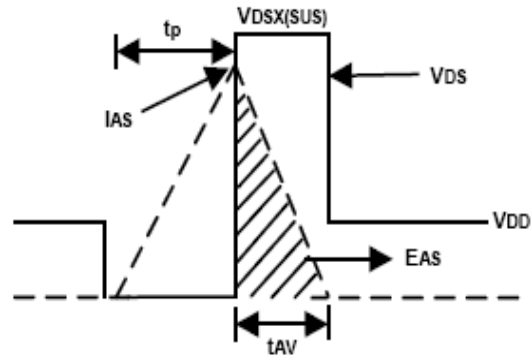
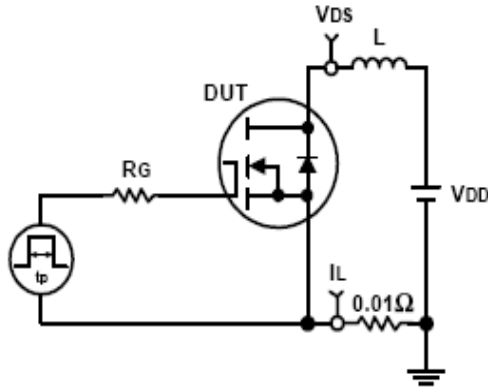
Capacitance



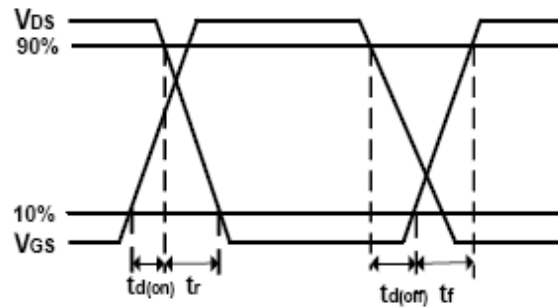
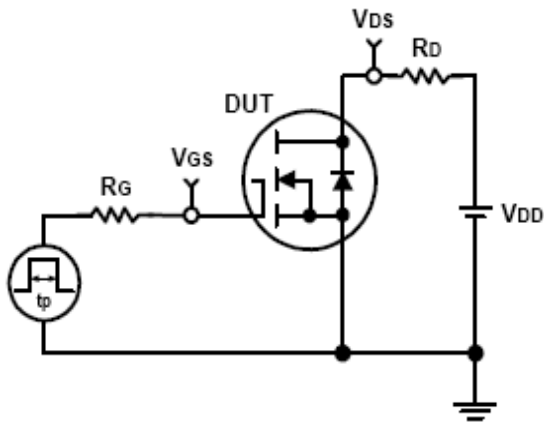
Gate Charge



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

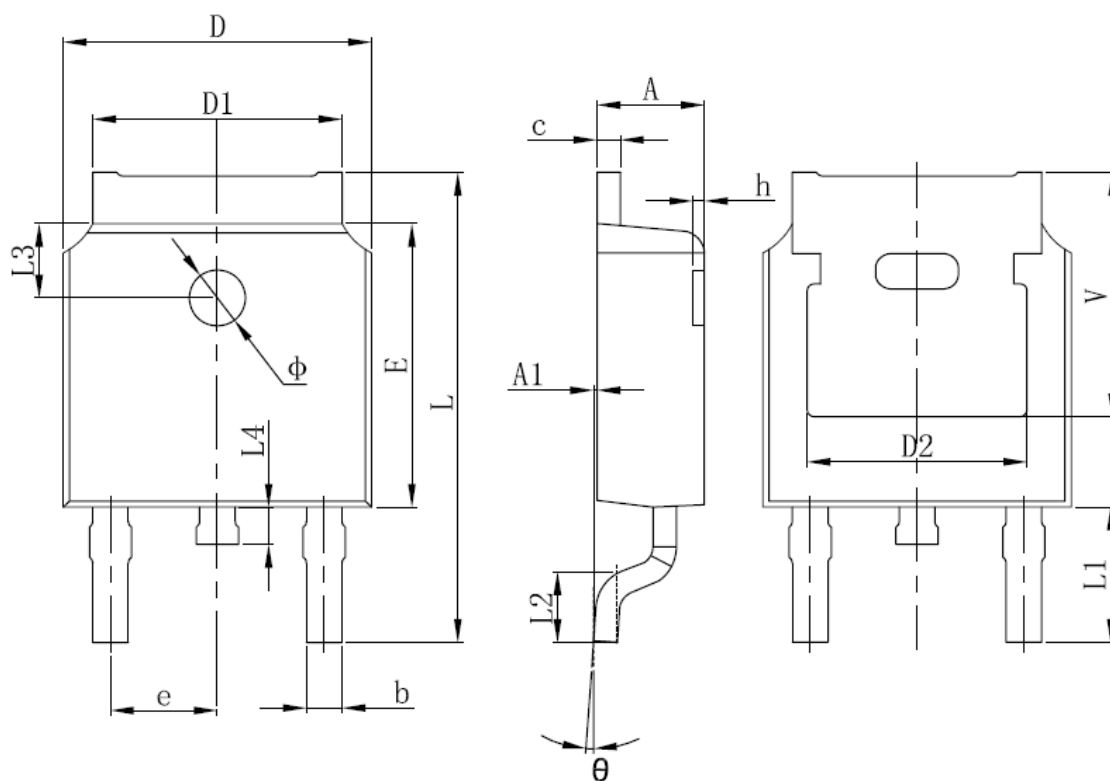


Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU6H1L	RU6H1L	TO-252	Tape&Reel	2500	13''	16mm

Package Information

TO252-2L



SYMBOL	MM		INCH		SYMBOL	MM		INCH	
	MIN	MAX	MIN	MAX		MIN	MAX	MIN	MAX
A	2.200	2.400	0.087	0.094	L	9.800	10.400	0.386	0.409
A1	0.000	0.127	0.000	0.005	L1	2.900 REF.		0.114 REF.	
b	0.660	0.860	0.026	0.034	L2	1.400	1.700	0.055	0.067
C	0.460	0.580	0.018	0.023	L3	1.600 REF.		0.063 REF.	
D	6.500	6.700	0.256	0.264	L4	0.600	1.000	0.024	0.039
D1	5.100	5.460	0.201	0.215	Φ	1.100	1.300	0.043	0.051
D2	4.830 REF.		0.190 REF.		θ	0°	8°	0°	8°
E	6.000	6.200	0.236	0.244	h	0.000	0.300	0.000	0.012
e	2.186	2.386	0.086	0.094	V	5.350 REF.		0.211 REF.	

ALL DIMENSIONS REFER TO JEDEC STANDARD
DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS

Customer Service

Worldwide Sales and Service:

Sales@ruichips.com

Technical Support:

Technical@ruichips.com

Investor Relations Contacts:

Investor@ruichips.com

Marcom Contact:

Marcom@ruichips.com

Editorial Contact:

Editorial@ruichips.com

HR Contact:

HR@ruichips.com

Legal Contact:

Legal@ruichips.com

Shen Zhen RUICHIPS Semiconductor CO., LTD

Room 501, the 5floor An Tong Industrial Building,
NO.207 Mei Hua Road Fu Tian Area Shen Zhen City, CHINA

TEL: (86-755) 8311-5334

FAX: (86-755) 8311-4278

E-mail: Sales-SZ@ruichips.com